NSN 5961-01-215-4064

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View Online at https://aerobasegroup.com/nsn/5961-01-215-4064

Inclosure Material:

Metal

Overall Length:

0.260 inches

Terminal Length:

0.500 inches

Overall Diameter:

0.335 inches

Internal Configuration:

Junction contact

Mounting Method:

Terminal

Terminal Circle Diameter:

0.200 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

-100.0 breakdown voltage, collector-to-base, emitter open and -75.0 breakdown voltage, collector-to-emitter, base open and -90.0 breakdown voltage, collector-to-emitter, with specified resistance between base and emitter and -7.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

Between 2.00 amperes source cutoff current and 0.20 amperes source cutoff current

Power Rating Per Characteristic:

10.0 watts small-signal input power, common-collector preset

Transfer Ratio:

130.0 static forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnp

Precious Material And Location:

Leads gold

Precious Material:

Gold

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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